

HALOGEN FREE

## Silicon PIN Photodiode



# DESCRIPTION

VBP104S and VBP104SR are high speed and high sensitive PIN photodiodes. It is a surface mount device (SMD) including the chip with a 4.4 mm<sup>2</sup> sensitive area detecting visible and near infrared radiation.

#### **FEATURES**

- Package type: surface mount
- Package form: GW, RGW



- Radiant sensitive area (in mm<sup>2</sup>): 4.4
- · High photo sensitivity
- · High radiant sensitivity
- · Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity:  $\varphi = \pm 65^{\circ}$
- Floor life: 168 h, MSL 3, acc. J-STD-020
- · Lead (Pb)-free reflow soldering
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

#### **APPLICATIONS**

• High speed photo detector

PRODUCT SUMMARY				
COMPONENT	I <sub>ra</sub> (μΑ)	φ (deg)	λ <sub>0.1</sub> (nm)	
VBP104S	35	± 65	430 to 1100	
VBP104SR	35	± 65	430 to 1100	

#### Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VBP104S	Tape and reel	MOQ: 1000 pcs, 1000 pcs/reel	Gullwing		
VBP104SR	Tape and reel	MOQ: 1000 pcs, 1000 pcs/reel	Reverse gullwing		

### Note

· MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	60	V	
Power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>V</sub>	215	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T <sub>amb</sub>	- 40 to + 100	°C	
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C	
Soldering temperature	Acc. reflow solder profile fig. 8	T <sub>sd</sub>	260	°C	
Thermal resistance junction/ambient		R <sub>thJA</sub>	350	K/W	



<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I <sub>F</sub> = 50 mA	V <sub>F</sub>		1	1.3	V
Breakdown voltage	$I_R = 100 \ \mu A, E = 0$	V <sub>(BR)</sub>	60			V
Reverse dark current	V <sub>R</sub> = 10 V, E = 0	I <sub>ro</sub>		2	30	nA
Diada assas Manas	V <sub>R</sub> = 0 V, f = 1 MHz, E = 0	C <sub>D</sub>		48		pF
Diode capacitance	V <sub>R</sub> = 3 V, f = 1 MHz, E = 0	C <sub>D</sub>		17	40	pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	Vo		350		mV
Temperature coefficient of Vo	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK <sub>Vo</sub>		- 2.6		mV/K
Short circuit current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	I <sub>k</sub>		32		μA
Temperature coefficient of Ik	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK <sub>lk</sub>		0.1		%/K
Reverse light current	$E_e$ = 1 mW/cm <sup>2</sup> , $\lambda$ = 950 nm, $V_R$ = 5 V	I <sub>ra</sub>	25	35		μΑ
Angle of half sensitivity		φ		± 65		deg
Wavelength of peak sensitivity		$\lambda_{p}$		940		nm
Range of spectral bandwidth		λ <sub>0.1</sub>		430 to 1100		nm
Noise equivalent power	V <sub>R</sub> = 10 V, λ = 950 nm	NEP		4 x 10 <sup>-14</sup>		W/√Hz
Rise time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega,$ $\lambda = 820 \text{ nm}$	t <sub>r</sub>		100		ns
Fall time	$V_R$ = 10 V, $R_L$ = 1 k $\Omega$ , $\lambda$ = 820 nm	t <sub>f</sub>		100		ns

## **BASIC CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

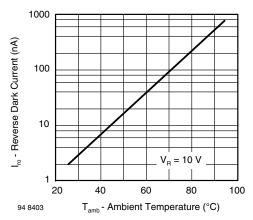


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

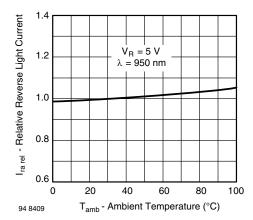


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature



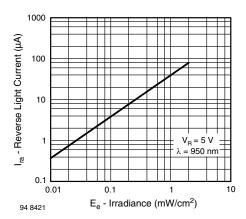


Fig. 3 - Reverse Light Current vs. Irradiance

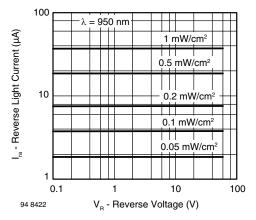


Fig. 4 - Reverse Light Current vs. Reverse Voltage

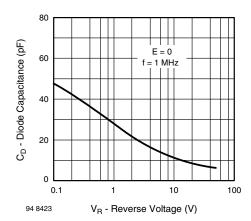


Fig. 5 - Diode Capacitance vs. Reverse Voltage

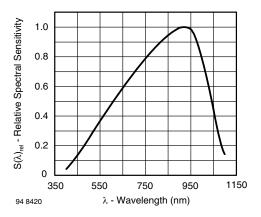


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

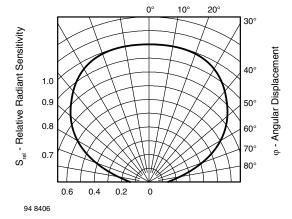
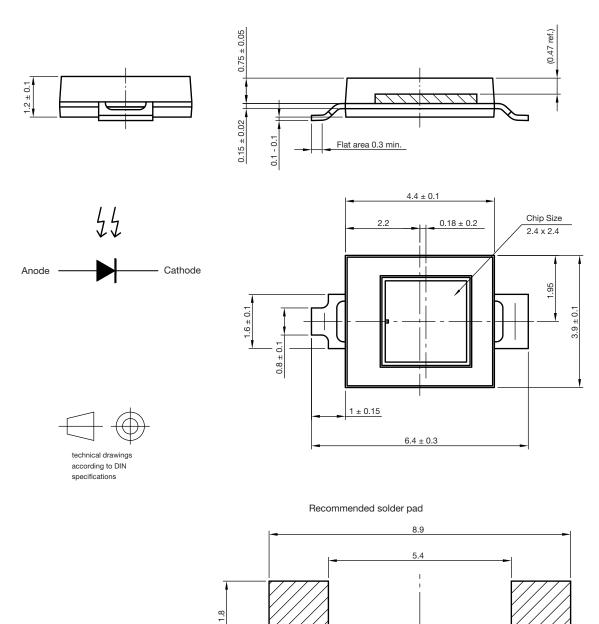


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

### **PACKAGE DIMENSIONS FOR VBP104S** in millimeters

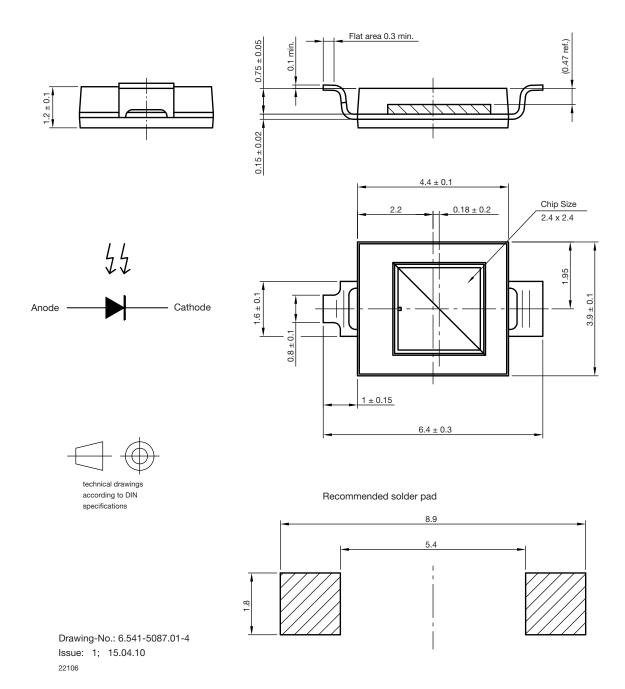


Drawing-No.: 6.541-5088.01-4

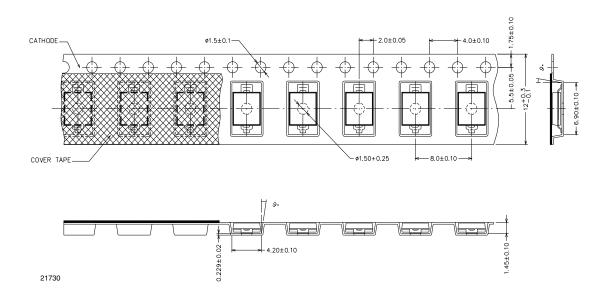
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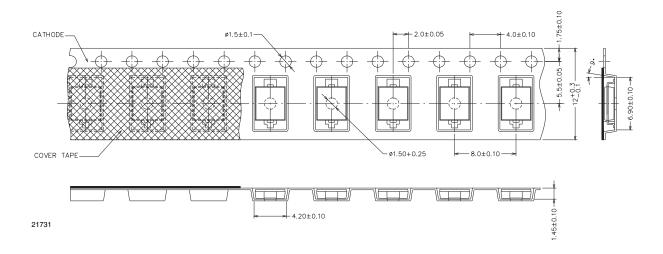
### **PACKAGE DIMENSIONS FOR VBP104SR** in millimeters



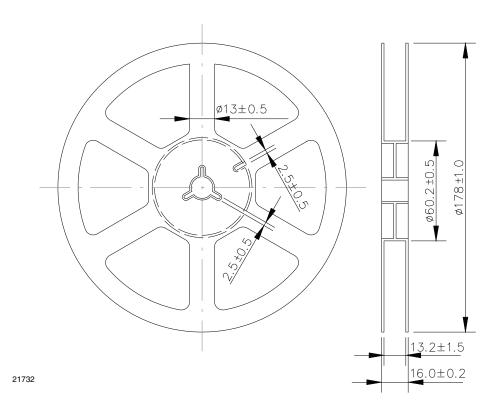
### **TAPING DIMENSIONS FOR VBP104S** in millimeters



## **TAPING DIMENSIONS FOR VBP104SR** in millimeters



### **REEL DIMENSIONS FOR VBP104S AND VBP104SR** in millimeters



### **SOLDER PROFILE**

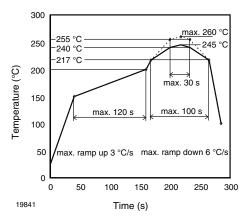


Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

### **DRYPACK**

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020:

Moisture sensitivity: level 3

Floor life: 168 h

Conditions: T<sub>amb</sub> < 30 °C, RH < 60 %

#### **DRYING**

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or recommended conditions:

192 h at 40 °C (+ 5 °C), RH < 5 %

or

96 h at 60 °C (+ 5 °C), RH < 5 %.



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